MBR1035以MBR1045

SWITCHMODE™ Power Rectifiers

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 10 A Total
- Pb-Free Packages are Available*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperatures for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B Machine Model C

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

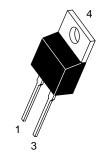


ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 10 AMPERES 35 to 45 VOLTS





MARKING DIAGRAM



A = Assembly Location

TO-220AC

CASE 221B

PLASTIC

Y = Year
WW = Work Week
G = Pb-Free Package
B10x5 = Device Code
x = 3 or 4
KA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MBR1035	TO-220	50 Units/Rail
MBR1035G	TO-220 (Pb-Free)	50 Units/Rail
MBR1045	TO-220	50 Units/Rail
MBR1045G	TO-220 (Pb-Free)	50 Units/Rail

營利MVINRATING 供应商

Rating	Symbol	Value	Unit V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}		
DC Blocking Voltage MBR1035 MBR1045	V_{R}	35 45	
Average Rectified Forward Current (T _C = 135°C, Per Device)	I _{F(AV)}	10	Α
Peak Repetitive Forward Current, (Square Wave, 20 kHz, T _C = 135°C)	I _{FRM}	10	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	150	А
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	1.0	Α
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{ heta JC}$	2.0	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	R_{\thetaJA}	60	

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 2) ($i_F = 10 \text{ Amps}$, $T_j = 125^{\circ}\text{C}$) ($i_F = 20 \text{ Amps}$, $T_j = 125^{\circ}\text{C}$) ($i_F = 20 \text{ Amps}$, $T_j = 25^{\circ}\text{C}$)	VF	1 1 1	0.55 0.67 0.78	0.57 0.72 0.84	V
Instantaneous Reverse Current (Note 2) (Rated dc Voltage, Tj = 125°C) (Rated dc Voltage, Tj = 25°C)	i _R	1 1	5.3 0.008	15 0.1	mA

^{2.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

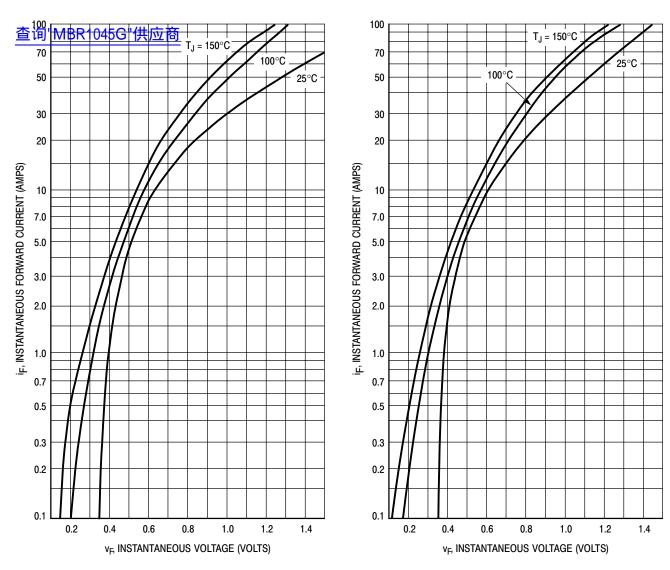
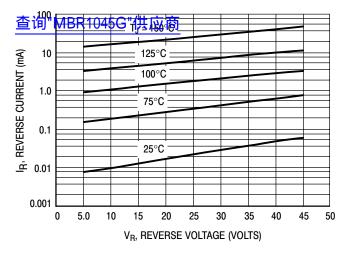


Figure 1. Maximum Forward Voltage

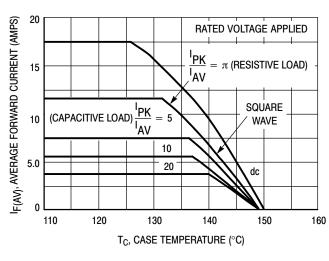
Figure 2. Typical Forward Voltage



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Figure 3. Maximum Reverse Current

Figure 4. Maximum Surge Capability



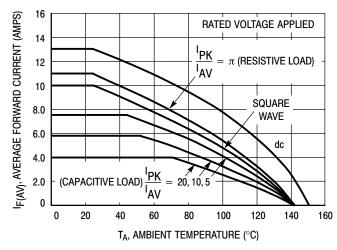
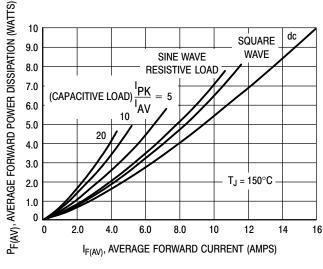


Figure 5. Current Derating, Infinite Heatsink





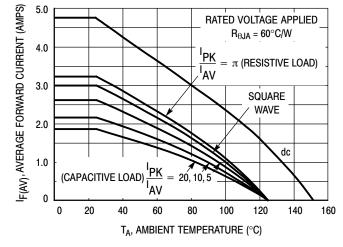


Figure 7. Forward Power Dissipation

Figure 8. Current Derating, Free Air

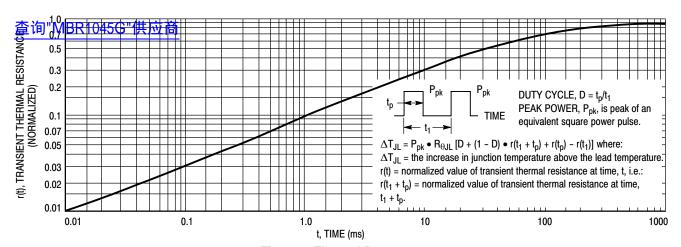


Figure 9. Thermal Response

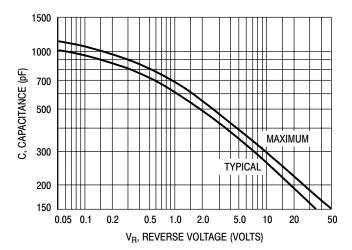
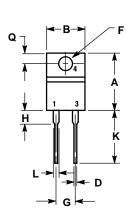


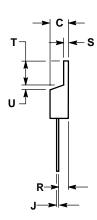
Figure 10. Capacitance

查询"MBR1045G"供应商

PACKAGE DIMENSIONS

TO-220 **PLASTIC** CASE 221B-04 ISSUE D





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
C	0.160	0.190	4.06	4.82	
D	0.025	0.035	0.64	0.89	
F	0.142	0.147	3.61	3.73	
G	0.190	0.210	4.83	5.33	
Н	0.110	0.130	2.79	3.30	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1 27	

STYLE 1: PIN 1. CATHODE

- 2. N/A 3. ANODE
- 4. CATHODE

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